



Released

GRF5110

28.8 dBm Power-LNA™
Tuning Range: 1.5 – 3.8 GHz



Product Description

GRF5110 is a high linearity PA /Linear Driver with low noise figure (NF). It delivers excellent P1dB, IP3 and NF over a wide range of frequencies with fractional bandwidths of roughly 5 to 10%.

The device can be tuned over a wide range of frequencies from around 1.5 GHz to 3.8 GHz.

Consult with the GRF applications engineering team for custom tuning/evaluation board data and device s-parameters.

Features

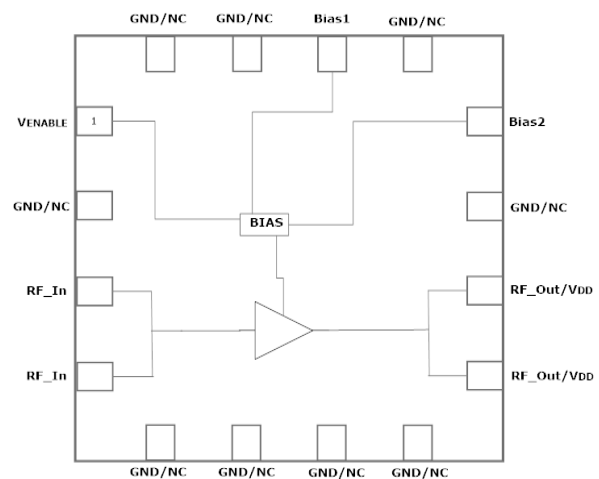
Reference: 5V/160mA/1.9GHz

- Gain: 15.0 dB
- OP1dB: 28.8 dBm
- OIP3: 46.0 dBm
- Eval Board NF:0.9 dB

- Flexible Bias Voltage and Current
- Process: GaAs pHEMT

Applications

- Power Amplifier
- Linear Driver Amplifier for High PAR Waveforms
- Multi-stage LNA



3.0 x 3.0 mm QFN-16



Released

GRF5110

28.8 dBm Power-LNA™
Tuning Range: 1.5 – 3.8 GHz

Absolute Ratings:

Parameter	Symbol	Min.	Max.	Unit
Drain Voltage	V _{DD}		6.0	V
Transient Average RF Input Power: (Load VSWR < 2:1; Duration: <1 hour)	P _{IN MAX}		24.0	dBm
Operating Temperature (Package Heat Sink)	T _{AMB}	-40	105	°C
Maximum Channel Temperature (MTTF > 10 ⁶ Hours)	T _{MAX}		170	°C
Maximum Dissipated Power	P _{DISS MAX}		1.0	W
Electrostatic Discharge:				
Charged Device Model: (TBD)	CDM	1500		V
Human Body Model:	HBM	250		V
Storage:				
Storage Temperature	T _{STG}	-65	150	°C
Moisture Sensitivity Level	MSL		1	–



Caution! ESD Sensitive Device

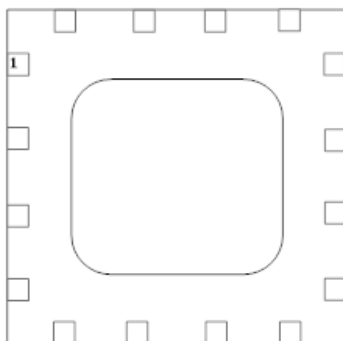


Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

Note: For package dimensions and manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF5110 landing page: **Manufacturing Note—MN-001 Product Tape and Reel, Solderability and Package Outline Specification.**

[Link to manufacturing note](#)

Pin Out (Top View)



Pin Assignments:

Pin	Name	Description	Note
1	V _{ENABLE}	Enable Voltage Input	V _{ENABLE} and series resistor set I _{DDQ} . V _{ENABLE} < =0.2 volts disables device. On-die pull-down resistor will turn the part off if this node is allowed to float.
2	NC	No Connect or Ground	No internal connection to die
3	RF_In	RF Input	Pins 3-4 tied together on system board
4	RF_In	RF Input	Pins 3-4 tied together on system board
5	NC	No Connect or Ground	No internal connection to die
6	NC	No Connect or Ground	No internal connection to die
7	NC	No Connect or Ground	No internal connection to die
8	NC	No Connect or Ground	No internal connection to die
9	RF_Out/V _{DD}	PA Output/Bias	Pins 9-10 tied together on system board. Supply V _{DD} here.
10	RF_Out/V _{DD}	PA Output/Bias	Pins 9-10 tied together on system board. Supply V _{DD} here.
11	NC	No Connect or Ground	No internal connection to die
12	Bias2	Bias Circuit Supply	Connect to V _{DD} through external resistor
13	NC	No Connect or Ground	No internal connection to die
14	Bias1	Bias Circuit Ground	Consult application schematic
15	NC	No Connect or Ground	No internal connection to die
16	NC	No Connect or Ground	No internal connection to die
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.



Released

GRF5110

28.8 dBm Power-LNA™
Tuning Range: 1.5 – 3.8 GHz

Nominal Operating Parameters:

Parameter	Symbol	Specification			Unit	Condition
		Min.	Typ.	Max.		
Target Performance (1.7 to 2.2 GHz Tune)						Bias: 5.0 V and 160 mA unless otherwise noted. (+25C)
Test Frequency	F _{TEST}		1.9		GHz	
Gain	S(2,1)	14.0	15.0		dB	
Noise Figure (Evaluation Board)	NF		0.9		dB	
Output 1dB Compression Point	OP1dB	27.3	28.8		dBm	
Output Third Order Intercept Point	OIP3		46.0		dBm	
Switching Rise Time	T _{RISE}		100		ns	
Switching Fall Time	T _{FALL}		800		ns	
Quiescent Supply Current	I _{DDQ}		160	190	mA	V _{DD} =V _{enable} =5.0volts R _{bias} : 5k ohms
Enable Current	I _{ENABLE}		2.0		mA	
Disabled Mode						
Supply Current (Leakage)	I _{DD}		30		uA	
Thermal Data						
Thermal Resistance: (IR Scan Method)	Θ _{JC}		80		°C/W	
Channel Temperature @ +85C Reference (package heat sink)	T _{CHANNEL}		149		°C	V _{DD} : 5.0 volts; I _{DDQ} : 160 mA P _{DISS} : 800 mW; No RF

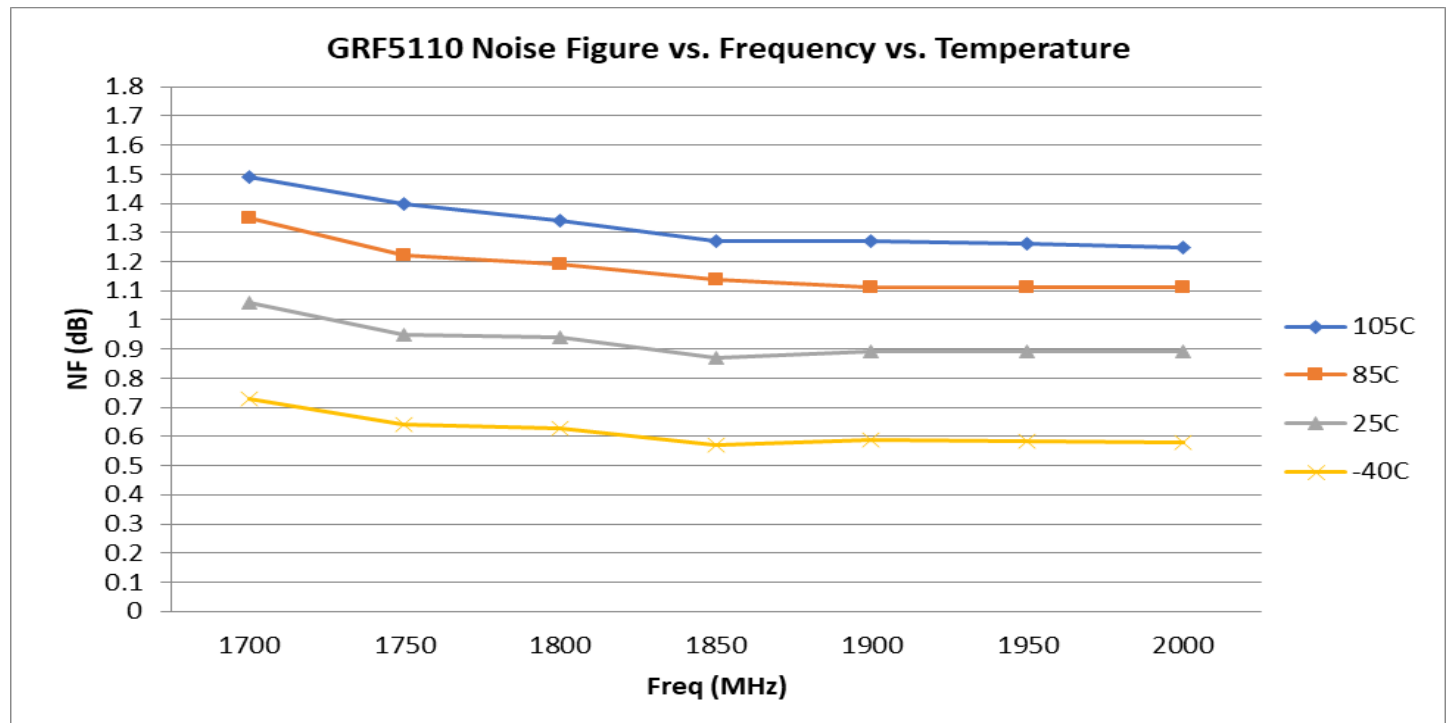
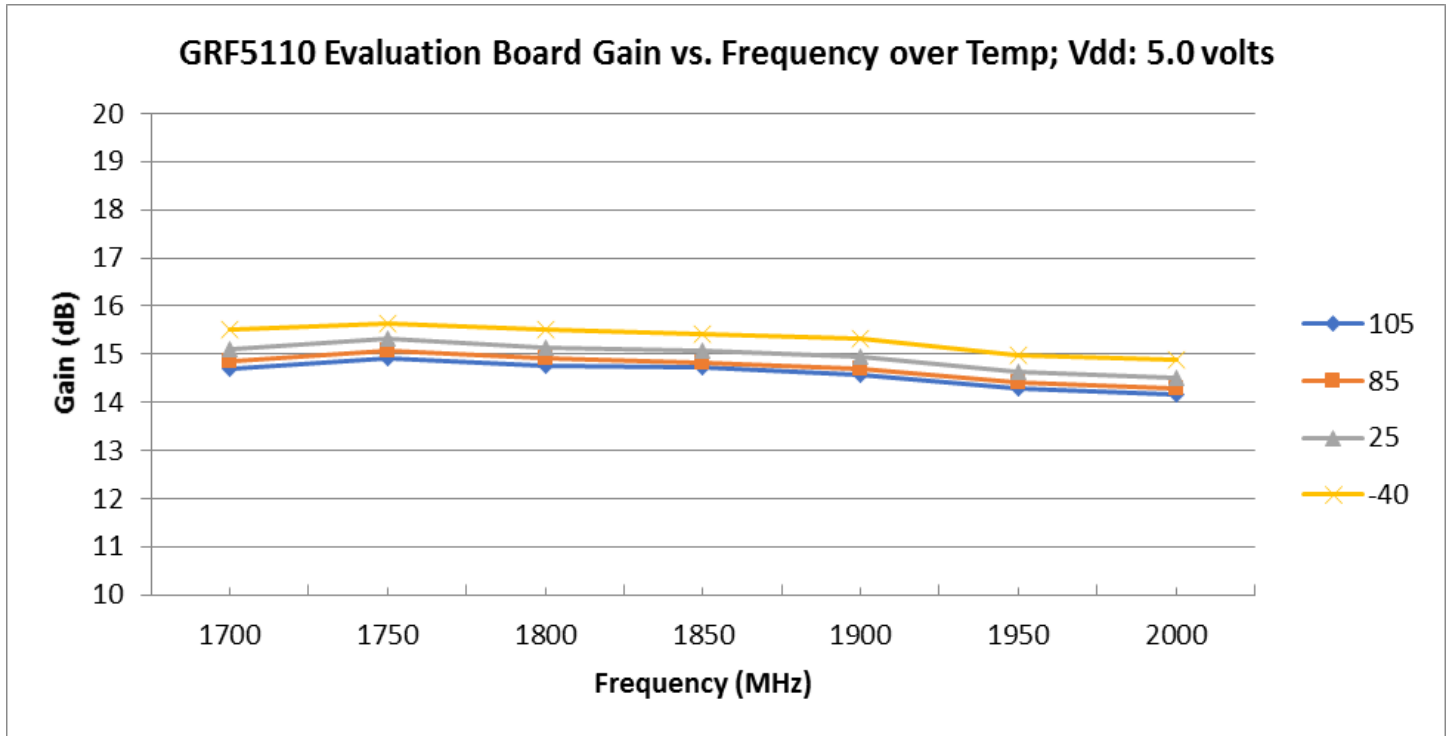


Released

GRF5110

28.8 dBm Power-LNA™
Tuning Range: 1.5 – 3.8 GHz

GRF5110 Evaluation Board Measured Data: (1.7 to 2.0 GHz Tune)



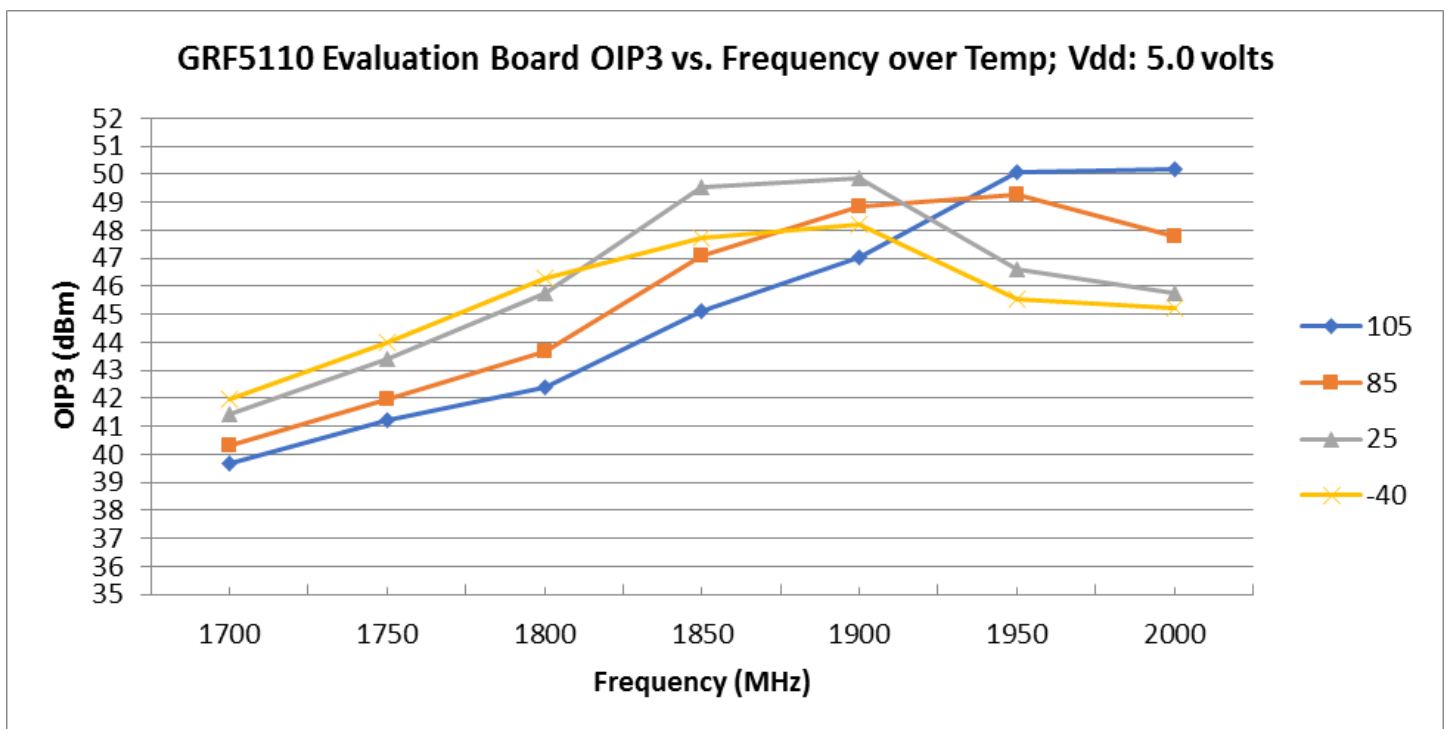
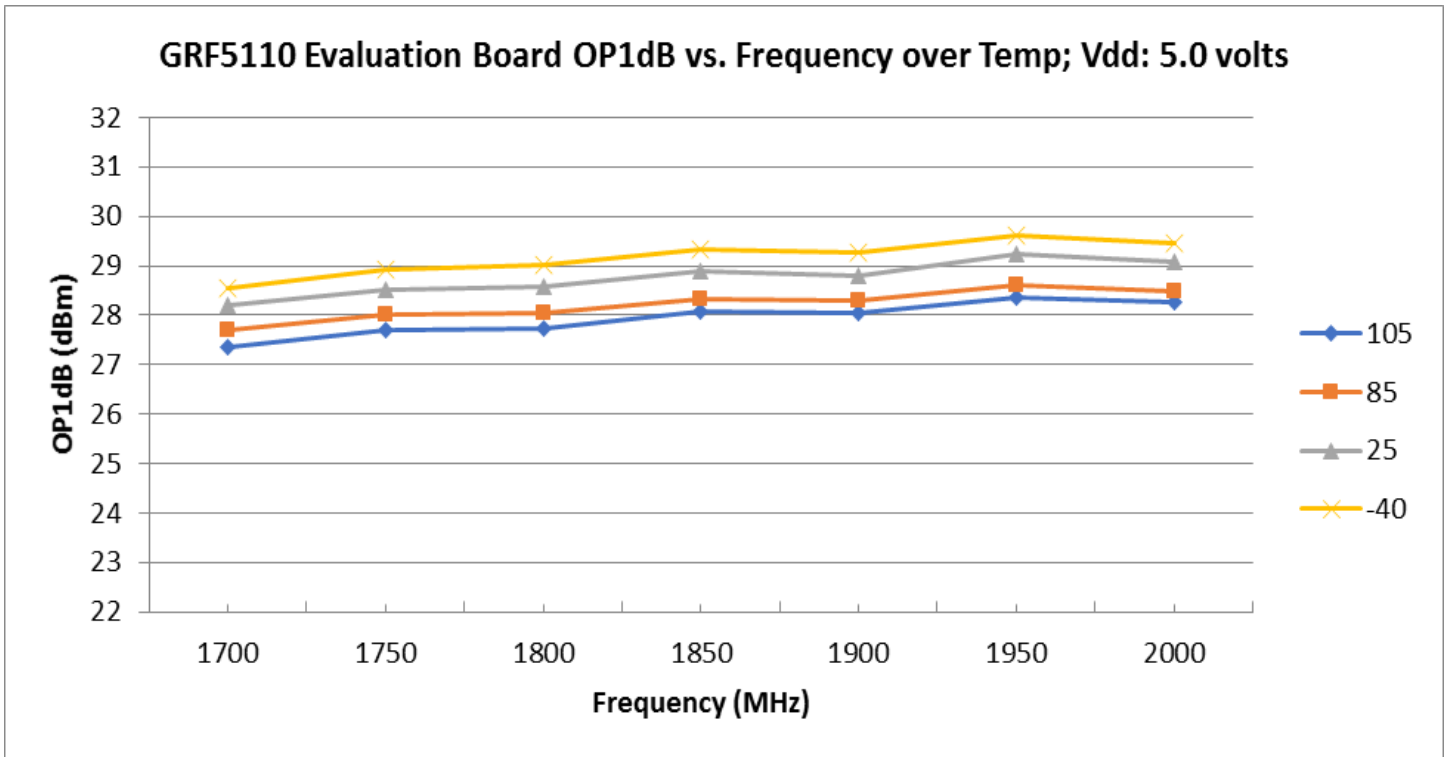


Released

GRF5110

28.8 dBm Power-LNA™
Tuning Range: 1.5 – 3.8 GHz

GRF5110 Evaluation Board Measured Data: (1.7 to 2.0 GHz Tune)



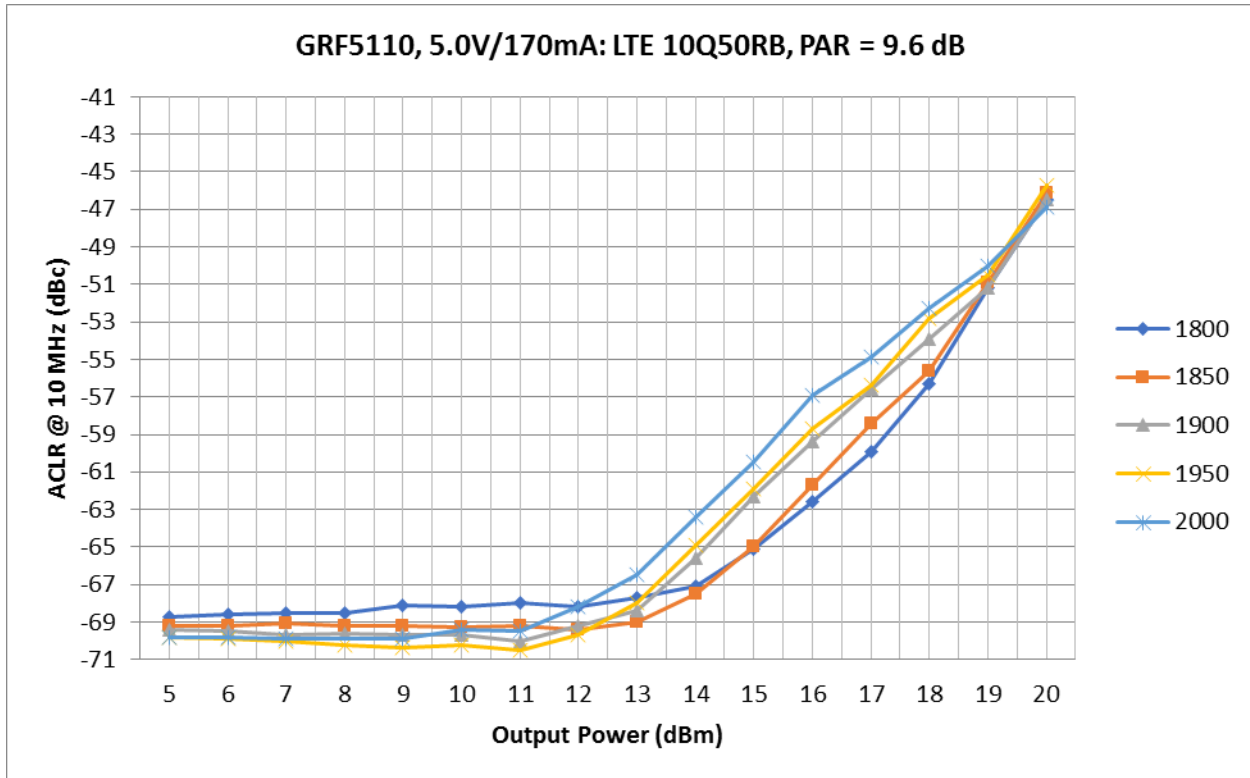


Released

GRF5110

28.8 dBm Power-LNA™
Tuning Range: 1.5 – 3.8 GHz

GRF5110 Evaluation Board Measured Data: (1.7 to 2.0 GHz Tune)



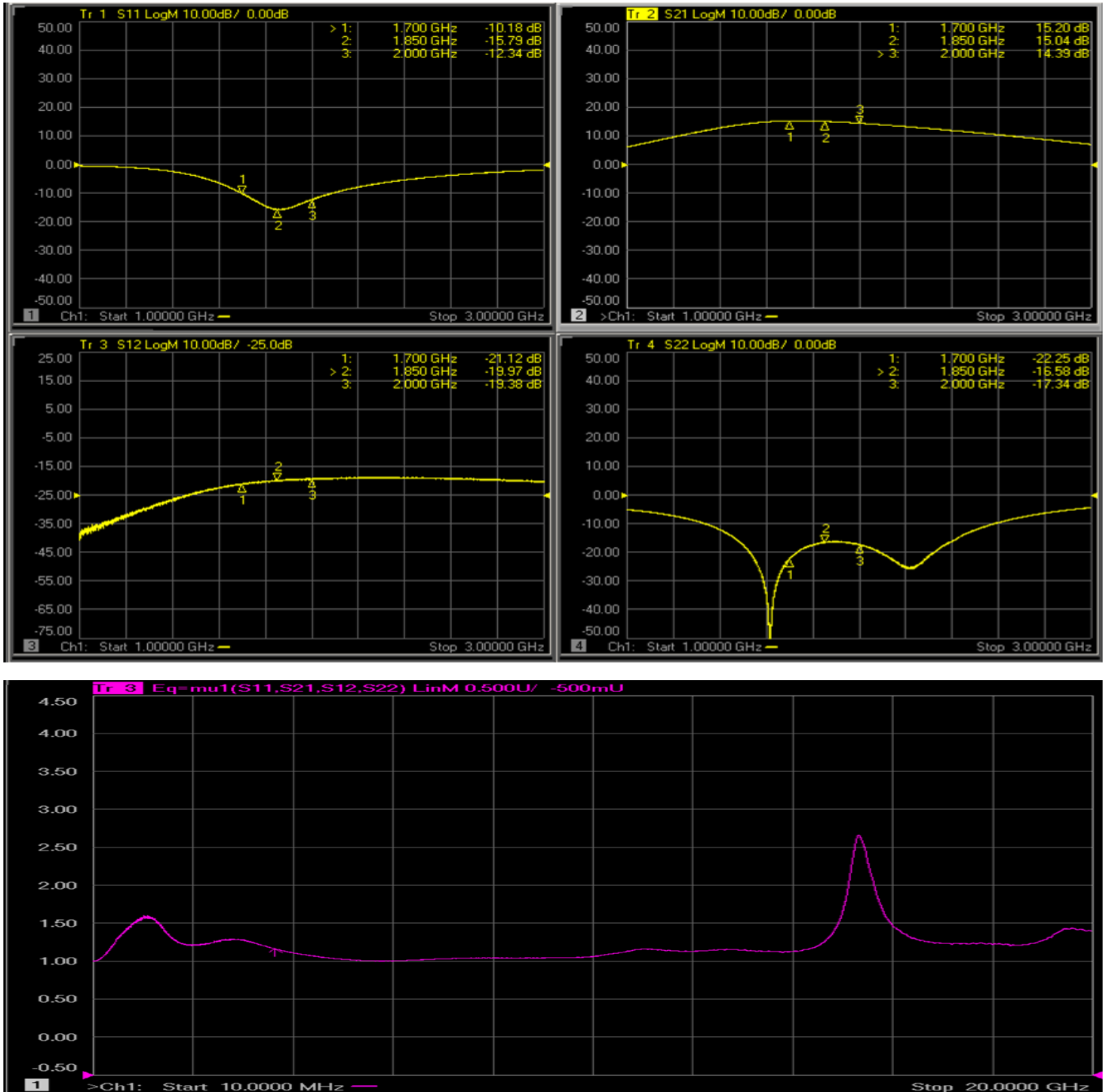


Released

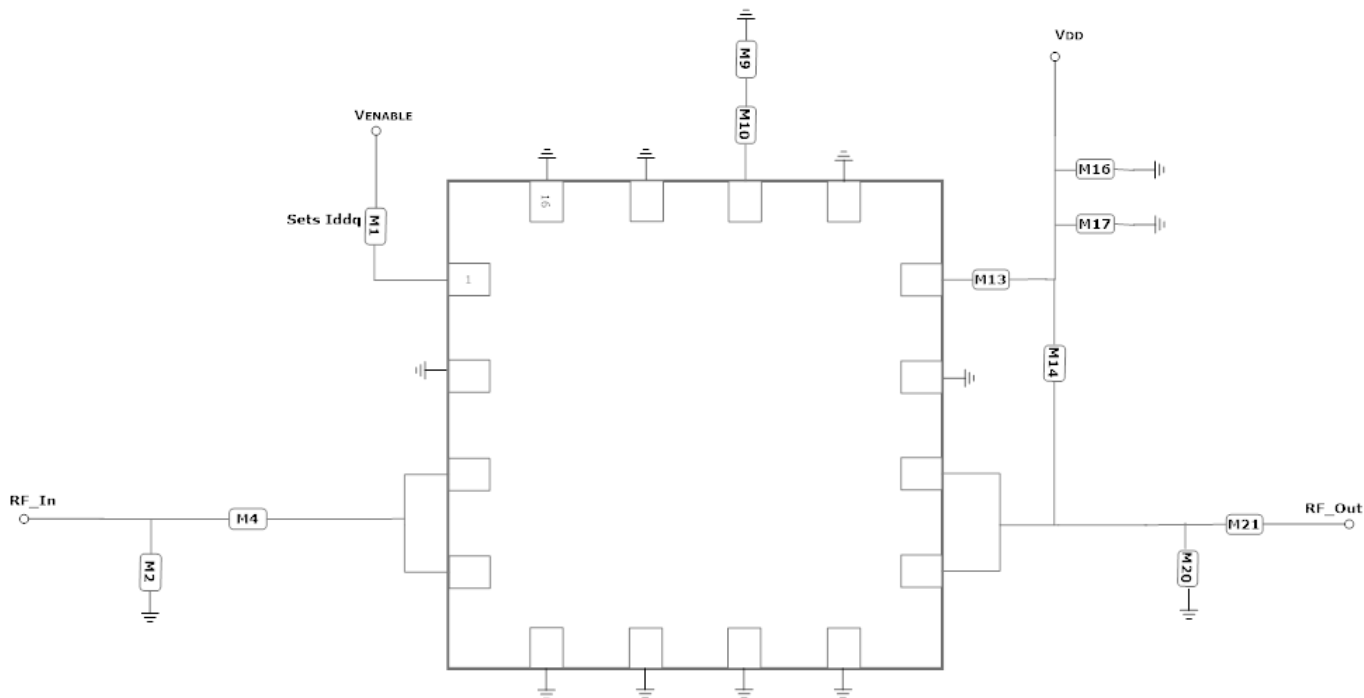
GRF5110

28.8 dBm Power-LNA™
Tuning Range: 1.5 – 3.8 GHz

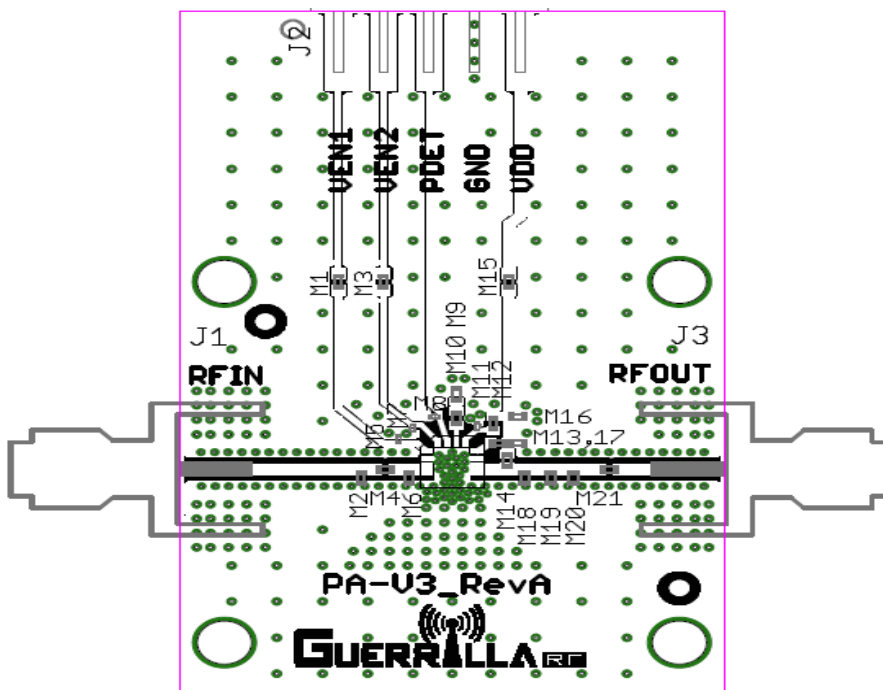
GRF5110 Evaluation Board S-Parms: (1.7 to 2.0 GHz Tune)



Note: Mu factor ≥ 1.0 implies unconditional stability.



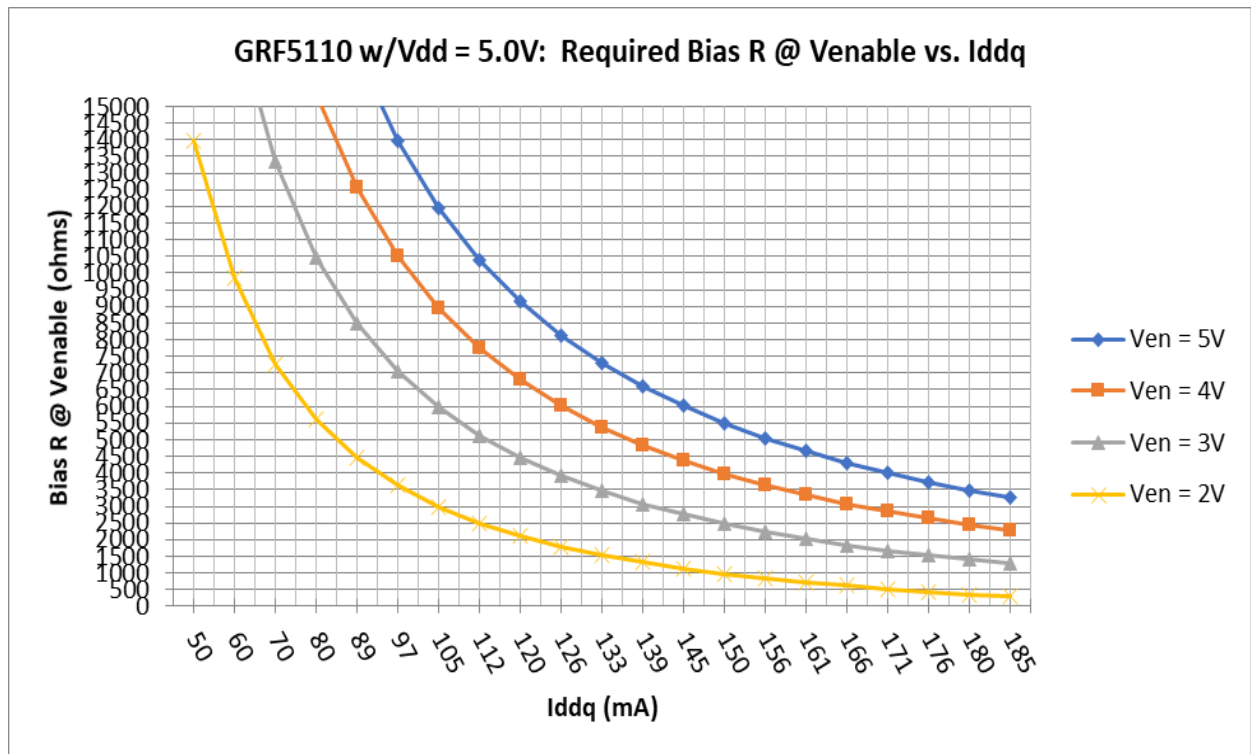
GRF5110 Application Schematic: (1.7 to 2.0 GHz)



GRF5110 Evaluation Board Assembly Drawing

GRF5110 Evaluation Board BOM: (1.7–2.0 GHz)

Component	Type	Manufacturer	Family	Value	Package Size	Substitution
M1 (See curves)	Resistor	Various	5%	Sets Iddq	0402	ok
M2	Inductor: High Q	Coilcraft	HP	2.7 nH	0402	ok
M4	Capacitor: High Q	Murata	GJM	2.0 pF	0402	ok
M9	Resistor	Various	5%	0 Ohm	0402	ok
M10	Inductor	Murata	LQP/LQG	12 nH	0402	ok
M13	Resistor	Various	5%	0 Ohm	0402	ok
M14	Inductor: High Q	Coilcraft	HP	18 nH	0402	ok
M16	Capacitor	Murata	GRM	0.1 uF	0402	ok
M17	Capacitor	Murata	GRM	100 pF	0402	ok
M20	Capacitor	Murata	GJM	1.5 pF	0402	ok
M21	Capacitor	Murata	GJM	10 pF	0402	ok



GRF5110 Bias Resistor (M1) Selection Curves



Released

GRF5110

28.8 dBm Power-LNA™

Tuning Range: 1.5 – 3.8 GHz

Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

Information in this datasheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

This datasheet, including the information contained in it, is provided by Guerrilla RF as a service to its customers and may be used for informational purposes only by the customer. Guerrilla RF assumes no responsibility for errors or omissions on this datasheet or the information contained herein. Information provided is believed to be accurate and reliable, however, no responsibility is assumed by Guerrilla RF for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. Guerrilla RF assumes no liability for any datasheet, datasheet information, materials, products, product information, or other information provided hereunder, including the sale, distribution, reproduction or use of Guerrilla RF products, information or materials.

No license, whether express, implied, by estoppel, by implication or otherwise is granted by this datasheet for any intellectual property of Guerrilla RF, or any third party, including without limitation, patents, patent rights, copyrights, trademarks and trade secrets. All rights are reserved by Guerrilla RF.

All information herein, products, product information, datasheets, and datasheet information are subject to change and availability without notice. Guerrilla RF reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice. Guerrilla RF may further change its datasheet, product information, documentation, products, services, specifications or product descriptions at any time, without notice. Guerrilla RF makes no commitment to update any materials or information and shall have no responsibility whatsoever for conflicts, incompatibilities, or other difficulties arising from any future changes.

GUERRILLA RF INFORMATION, PRODUCTS, PRODUCT INFORMATION, DATASHEETS AND DATASHEET INFORMATION ARE PROVIDED "AS IS" AND WITHOUT WARRANTY OF ANY KIND, WHETHER EXPRESS, IMPLIED, STATUTORY, OR OTHERWISE, INCLUDING FITNESS FOR A PARTICULAR PURPOSE OR USE, MERCHANTABILITY, PERFORMANCE, QUALITY OR NON-INFRINGEMENT OF ANY INTELLECTUAL PROPERTY RIGHT; ALL SUCH WARRANTIES ARE HEREBY EXPRESSLY DISCLAIMED. GUERRILLA RF DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. GUERRILLA RF SHALL NOT BE LIABLE FOR ANY DAMAGES, INCLUDING BUT NOT LIMITED TO ANY SPECIAL, INDIRECT, INCIDENTAL, STATUTORY, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS THAT MAY RESULT FROM THE USE OF THE MATERIALS OR INFORMATION, WHETHER OR NOT THE RECIPIENT OF MATERIALS HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGE.

Customers are solely responsible for their use of Guerrilla RF products in the Customer's products and applications or in ways which deviate from Guerrilla RF's published specifications, either intentionally or as a result of design defects, errors, or operation of products outside of published parameters or design specifications. Customers should include design and operating safeguards to minimize these and other risks. Guerrilla RF assumes no liability or responsibility for applications assistance, customer product design, or damage to any equipment resulting from the use of Guerrilla RF products outside of stated published specifications or parameters.

Guerrilla RF Proprietary Information. Guerrilla RF™ and the composite logo of Guerrilla RF™ are trademarks of Guerrilla RF, Inc. ©2014 Guerrilla RF, Inc. All rights reserved.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А